

DESCRIPTION

The GC4700 series diodes are specially processed PIN diodes designed for use in passive or active limiters at frequencies through Ku band. Thirteen categories of devices are offered for flexibility in design of low, medium and high power limiters. Low VB limiters have thinner I regions for faster turn-on time and better flat leakage. Microsemi also manufactures “gold doped” limiters for fastest turn on time. In addition, we manufacture high voltage dual junction limiters for superior peak and CW power handling.

This series of diodes meets RoHS requirements per EU Directive 2002/95/EC.

KEY FEATURES

- Available as packaged devices or as chips for hybrid applications
- Low Loss
- Suitable for applications to 18GHz
- Excellent flat leakage performance
- Low 1 dB compression point
- Gold Doped Diodes for Fast Turn On
- RoHS Compliant¹

¹ Most of our devices are supplied with Gold plated terminations. Other terminal finishes are available on request. Consult factory for details.

APPLICATIONS

A diode limiter is a power-sensitive variable attenuator that uses the non-linear properties of the diode to provide an impedance mismatch when sufficient amounts of RF power are incident on the device. The output power is reduced to a level that will not overdrive a receiver, burn out a mixer, etc. For varying input power levels in excess of the diode’s threshold level, the limiter’s output power tends to remain constant.

A passive limiter is one in which the limiter diodes are “turned on” by the RF signal itself. An active limiter is one in which the limiter diodes are “turned on” primarily by an external bias current typically supplied by a Schottky detector diode which senses the incident signal.

Since limiter diodes are not designed to dissipate large amounts of power, the limiter must reflect or divert the excess incident power back to the source or to another load (i.e. via a circulator, hybrid coupler, etc.).

Limiter diodes may be used in wave guides, coax, microstrip, stripline or other media. Single or cascaded devices may be used, depending on power levels.

APPLICATIONS/BENEFITS

- Receiver protection circuits
- Amplifier Protection

**ABSOLUTE MAXIMUM RATINGS AT 25° C
(UNLESS OTHERWISE SPECIFIED)**

| Rating | Symbol | Value | Unit |
|---|------------------|-------------|------|
| Maximum Leakage Current @80% of minimum Rated Vb | I _r | 0.5 | uA |
| Operating Temperature | T _{op} | -55 to +150 | °C |
| Storage Temperature | T _{stg} | -65 to +150 | °C |

IMPORTANT: For the most current data, consult our website: www.MICROSEMI.com



These devices are ESD sensitive and must be handled using ESD precautions.

CHIP ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)

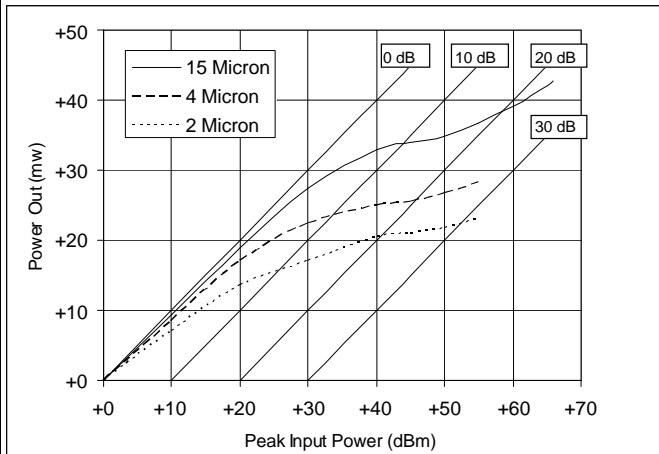
| Model # | V _b (Min) | C _{j0} (Typ) | C _{j-6} (Max) | C _{j-50} (Max) | R _s (Typ) | T _L (Typ) | θP ¹ (Typ) | θP ² (Max) |
|---------------------------|---------------------------------|--------------------------|---------------------------|----------------------------|-------------------------|-------------------------|---------------------------------|---------------------------------|
| | I _R =10μA (Volts) | @0V (pF) | @-6V (pF) | @-50V (pF) | @10 mA (Ω) | (ns) | THERMAL RESISTANCE (°C/W) | THERMAL RESISTANCE (°C/W) |
| GC4701-00 | 20 | 0.20 | 0.15 | -- | 1.5 | 5 | 20 | 100 |
| GC4702-00 | 20 | 0.50 | 0.30 | -- | 1.2 | 10 | 12 | 80 |
| GC4711-00 | 45 | 0.20 | 0.15 | -- | 1.5 | 10 | 15 | 80 |
| GC4712-00 | 45 | 0.50 | 0.30 | -- | 1.2 | 15 | 10 | 60 |
| GC4713-00 | 45 | 0.70 | 0.50 | -- | 1.0 | 20 | 6 | 40 |
| GC4721-00 | 120 | 0.20 | 0.15 | -- | 1.5 | 50 | 1.2 | 40 |
| GC4722-00 | 120 | 0.60 | 0.30 | -- | 1.0 | 50 | 0.5 | 20 |
| GC4723-00 | 120 | 0.80 | 0.50 | -- | 0.5 | 100 | 0.3 | 15 |
| GC4731-00 | 15 | 0.12 | 0.10 | -- | 2.0 | 5 | 30 | 120 |
| GC4732-00 | 15 | 0.20 | 0.15 | -- | 1.5 | 5 | 20 | 80 |
| GC4741-00 | 30 | 0.12 | 0.10 | -- | 2.0 | 7 | 20 | 100 |
| GC4742-00 | 30 | 0.20 | 0.15 | -- | 1.5 | 7 | 15 | 70 |
| GC4750-002 ⁽³⁾ | 250 | -- | -- | 0.25 ⁽⁴⁾ | 3.0@50mA | 300 | 4 | 10 |

TYPICAL RF PERFORMANCE @ 25°C (unless otherwise specified)

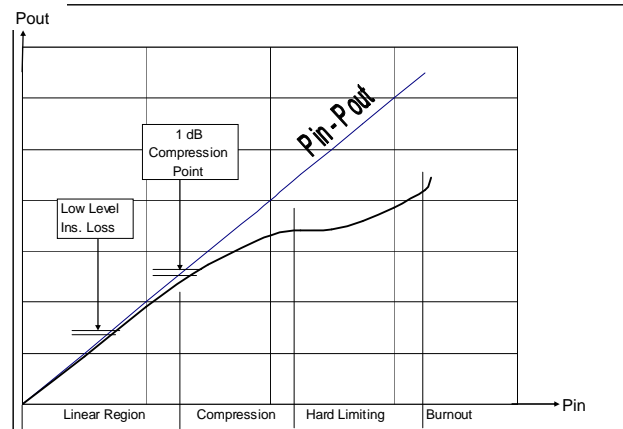
| Model Number | V _b (Min) | PEAK POWER P _{IN} @ 1 μ S (dBm) | TYPICAL LEAKAGE P _{OUT} (dBm) | TYPICAL THRESHOLD (dBm) | TYPICAL INS. LOSS I _L (dB) | MAXIMUM CW POWER (Watts) |
|--------------|-------------------------|---|---|-------------------------------|--|--------------------------------|
| GC4701 | 20 | +50 | +22 | +10 | 0.1 | 2 |
| GC4702 | 20 | +53 | +24 | +10 | 0.2 | 3 |
| GC4711 | 45 | +53 | +27 | +15 | 0.1 | 3 |
| GC4712 | 45 | +56 | +29 | +15 | 0.2 | 4 |
| GC4713 | 45 | +59 | +31 | +15 | 0.2 | 5 |
| GC4721 | 120 | +60 | +39 | +20 | 0.1 | 5 |
| GC4722 | 120 | +63 | +41 | +20 | 0.2 | 10 |
| GC4723 | 120 | +66 | +44 | +20 | 0.2 | 15 |
| GC4731 | 15 | +47 | +19 | +7 | 0.1 | 2 |
| GC4732 | 15 | +50 | +22 | +4 | 0.1 | 3 |
| GC4741 | 30 | +47 | +24 | +12 | 0.1 | 3 |
| GC4742 | 30 | +50 | +27 | +12 | 0.1 | 4 |
| GC4750 | 250 | +56 @10uS | +44 | +31 | 0.2 | 50 |

Notes

- 1) Pulse length 1 microsecond.
- 2) As measured in style 30 package
- 3) Available in 002 style or 115-2 package styles
- 4) C_J for 2 junctions in parallel @ V_R=50V

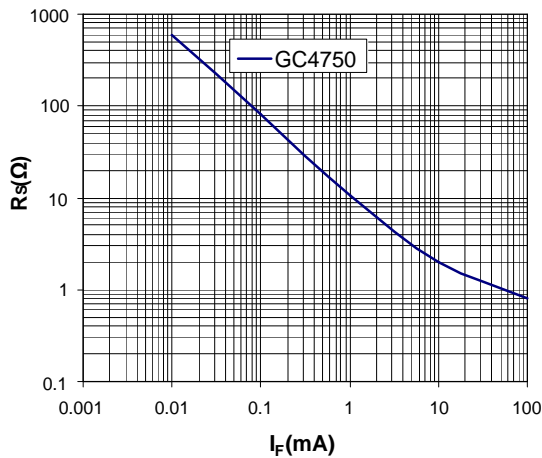
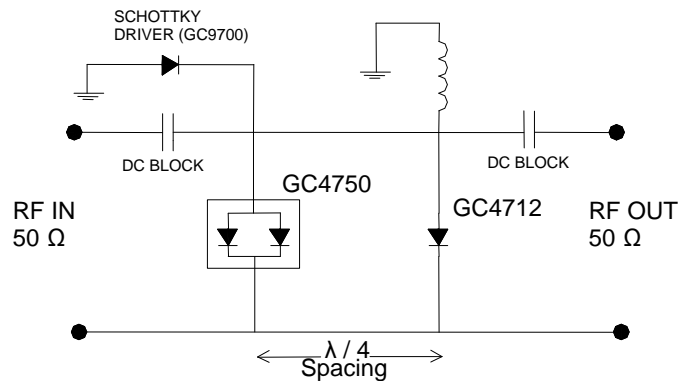
POWER LEAKAGE PERFORMANCE


Typical Power Leakage vs I Region Thickness

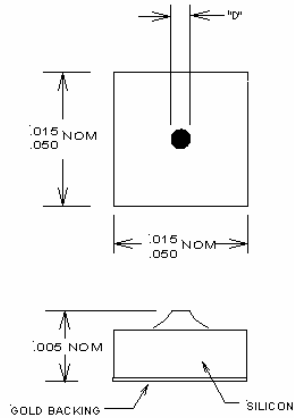
TRANSFER CHARACTERISTICS


Typical Limiter Transfer Characteristics

SERIES RESISTANCE

 Typical R_s Vs I_F Curve

HIGH POWER DUAL LIMITER DESIGN


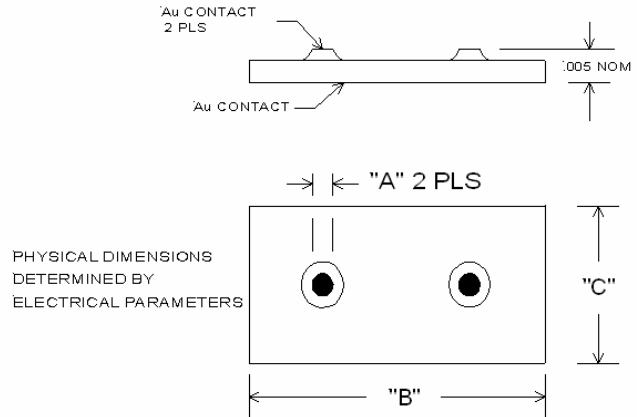
2 Stage Limiter with Schottky Driver

PACKAGE STYLE 00


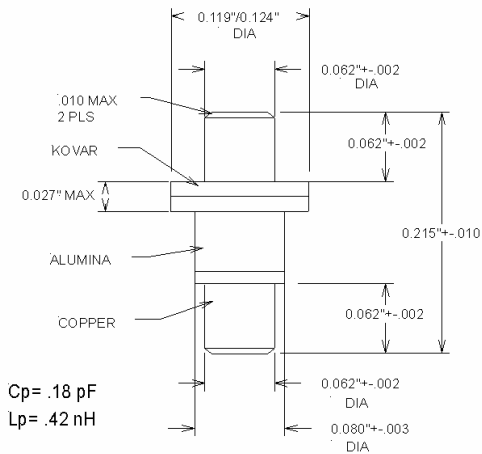
NOTES:
 1. TOP CONTACT, CHIP SIZE, AND CHIP THICKNESS DEPENDS ON DIODE PARAMETERS. CONSULT FACTORY.
 2. TOP AND BOTTOM CONTACTS GOLD.

Notes:

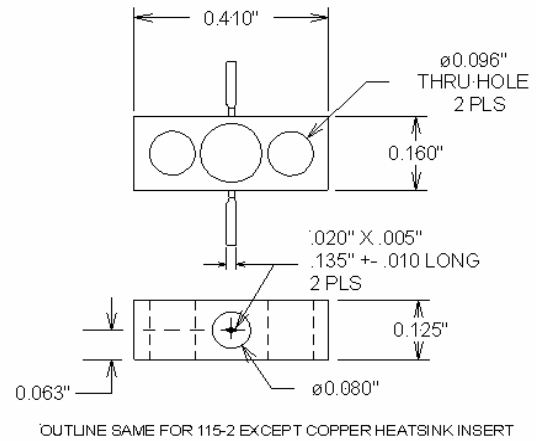
- Order as GC47xx – 00

DUAL CHIP STYLE 002

Notes:

- Order as GC47xx – 002

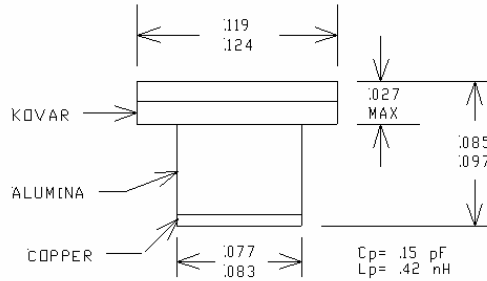
PACKAGE STYLE 30

Notes:

- Order as GC47xx – 30

PACKAGE STYLE 115-2

Notes:

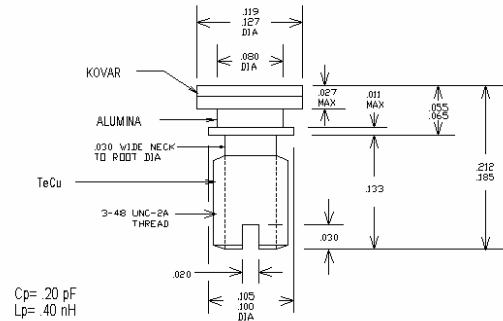
- Order as GC47xx – 115-2

**OTHER PACKAGE STYLES AVAILABLE ON REQUEST
 CONSULT FACTORY**

PACKAGE STYLE 35


Notes:

- Order as GC47xx – 35

PACKAGE SYLE 42


Notes:

- Order as GC47xx – 42

**OTHER PACKAGE STYLES AVAILABLE ON REQUEST
 CONSULT FACTORY**



Microsemi[®]

GC4701 - GC4750

CONTROL DEVICES – LIMITERS DIODES

RoHS COMPLIANT



NOTES

www.MICROSEMI.com

NOTES

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Microchip:

[GC4732-150A](#) [GC4731-150C](#) [GC4712-42](#) [GC4731-150A-AP](#) [GC4732-115-2](#) [GC4731-35](#) [GC4750-42](#) [GC4711-35](#)
[GC4711-92](#) [GC4713-154-4](#)

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С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

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- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
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- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

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- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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